

# T496X106M035AH4095

Aliases (DLA Drawing 04053-085Z)

T496 HRA, Tantalum, MnO2 Tantalum, HRA, 10 uF, 20%, 35 VDC, SMD, MnO2, Molded, Military, Fused, High Reliability, A (Non-ER), 1 Ohms, 4.3 mm, 2817 / 7343



Click [here](#) for the 3D model.

## General Information

Series	T496 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Military, Fused, High Reliability
Features	Internal Fuse, High Reliability
RoHS	No
Prop 65	<b>WARNING:</b> Cancer and reproductive harm - <a href="https://www.p65warnings.ca.gov/">https://www.p65warnings.ca.gov/</a>
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
Typical Component Weight	652.04 mg

## Dimensions

L	7.3mm +/-0.3mm
W	4mm +/-0.3mm
H	4mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
P	1.7mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

## Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

## Specifications

Capacitance	10 uF
Tolerance	20%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	A (Non-ER)
ESR	1000 mOhms (100kHz 25C)
Ripple Current	406 mA (rms, 100kHz 25C)
Leakage Current	3.5 uA (5min 25°C)
Testing and Reliability	Tested To Meet The Established Reliability

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